

Metric Prefixes

peta	P	10^{15}	1 000 000 000 000 000
tera	T	10^{12}	1 000 000 000 000
giga	G	10^9	1 000 000 000
mega	M	10^6	1 000 000
kilo	k	10^3	1 000
hecto	h	10^2	100
deca	da	10^1	10
one		10^0	1
deci	d	10^{-1}	0.1
centi	c	10^{-2}	0.01
milli	m	10^{-3}	0.001
micro	μ	10^{-6}	0.000 001
nano	n	10^{-9}	0.000 000 001
pico	p	10^{-12}	0.000 000 000 001
femto	f	10^{-15}	0.000 000 000 000 001

Ohm's Law $V = IR$, $I = \frac{V}{R}$, $R = \frac{V}{I}$

Battery Symbol

The side with the longer line is the positive side

Complex Numbers

- $z = x + iy = re^{i\theta} = r[\cos(\theta) + i\sin(\theta)]$
- $[r(\cos(\theta) + i\sin(\theta))]^n = r^n[\cos(n\theta) + i\sin(n\theta)]$
- $z^n = (re^{i\theta}) = r^n e^{in\theta}$
- $\frac{1}{i} = -i$
- $\sqrt[n]{z} = \sqrt[n]{r} e^{\frac{\theta}{n} + \frac{2k\pi}{n}}$ for $n \in \mathbb{N}^*$ (ints ≥ 0)
- $e^{j\theta} = \cos(\theta) + j\sin(\theta) \quad \left| \quad e^{-j\theta} = \cos(\theta) - j\sin(\theta) \right.$
- $\cos(\theta) = \frac{1}{2}(e^{j\theta} + e^{-j\theta}) \quad \left| \quad \sin(\theta) = \frac{1}{2j}(e^{j\theta} - e^{-j\theta}) \right.$
- normalized: $\text{sinc}(t) = \frac{\sin(\pi t)}{\pi t}$

$$\left| \frac{a}{b} \right| = \frac{|a|}{|b|}$$

$$\angle \frac{a}{b} = \angle a - \angle b$$

Trig

$$\begin{aligned} \cos(2a) &= \cos^2(a) - \sin^2(a) = 2\cos^2(a) - 1 = 1 - 2\sin^2(a) \\ \cos^2(a) + \sin^2(a) &= 1 \quad \left| \quad \sin(2a) = 2\sin(a)\cos(a) \right. \\ \cos^2(a) &= \frac{1}{2}(1 + \cos(2a)) \quad \left| \quad \sin^2(a) = \frac{1}{2}(1 - \cos(2a)) \right. \end{aligned}$$

Voltage Division between two non-zero points

$$V_{DD} \rightarrow R_1 \rightarrow V_1 \rightarrow R_2 \rightarrow V_{EE} \quad (\text{superposition})$$

$$V_1 = V_{DD} \frac{R_2}{R_1 + R_2} + V_{EE} \frac{R_1}{R_1 + R_2}$$

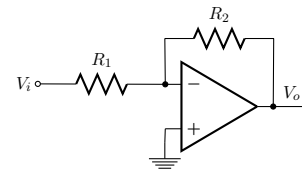
Node Plots

- magnitude is plotted in dB: $|T(j\omega)|_{dB} = 20 \log_{10} |T(j\omega)|$
- starts on y-axis at DC offset with slope 0
- just add together the bode plots of each individual pole, zero, and the DC offset
- poles always slope down, zeros slope up (applies for both magnitude and phase)
- dec=decade, e.g. from 10^0 to 10^1
- magnitude:
 - * Pole/Zero at origin: constant slope $\pm 20\text{dB/dec}$ for all ω ; 0dB at $\omega = 10^0 = 1$
 - * Pole/Zero at ω_0 : 0 for $\omega < \omega_0$ slope $\pm 20 \frac{dB}{dec}$ after
 - * Constant C : constant line at $20 \log_{10}(|C|)$
- phase:
 - * Pole at origin: constant $-\frac{\pi}{2}$ or -90°
 - * Zero at origin: constant $+\frac{\pi}{2}$ or $+90^\circ$
 - * Pole/Zero at ω_0 : 0 for $\omega < \frac{\omega_0}{10}$ slope linearly ($\pm 45^\circ/\text{dec}$) until $10\omega_0$ 0 slope for $\omega > 10\omega_0$
 - * Constant C : no effect (0 for all ω)

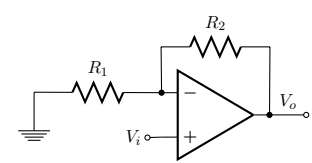
- Prof wants us to actually show the -3dB drop curve, not just a straight intersection

Solving systems with Op Amps

- only applies if the op-amp has feedback
- step 0: if the op amp is ideal, write out ideal properties:
 - * $V_+ = V_-$
 - * $I_- = 0, I_+ = 0$
 - * $A \approx \infty$
- avoid doing KCL/KVL directly on the output node of the op amp
- ignore resistors from a point at 0V to ground

Op Amp Equations

Inverting Amplifier



Non-Inverting Amplifier

- ideal open-loop behavior: $(V_p - V_n) > 0 \rightarrow V_o = V_{DD}$
 $(V_p - V_n) < 0 \rightarrow V_o = -V_{DD}$
- general form: $T(s) = \frac{K_0}{1 + \frac{s}{\omega_0}}$
 - * $T(0) = K_0$: DC offset. For these simple ones, it's equal to ideal response
 - * $\omega_0 = \frac{\omega_t}{1 + R_2/R_1}$
- inverting op amp:
 - * ideal: $T(s) = \frac{V_o}{V_i} = -\frac{R_2}{R_1}$
 - * non-ideal: $T(s) = \frac{V_o}{V_i} = \frac{-R_2/R_1}{1 + \frac{1+R_2/R_1}{A(s)}} = \frac{-R_2/R_1}{1 + \frac{s}{\left(\frac{\omega_t}{1+R_2/R_1}\right)}} = \frac{-R_2/R_1}{1 + \frac{s}{\omega_0}}$
- non-inverting op-amp:
 - * ideal: $T(s) = \frac{V_o}{V_i} = 1 + \frac{R_2}{R_1}$
 - * non-ideal: $T(s) = \frac{V_o}{V_i} = \frac{1+R_2/R_1}{1 + \frac{1+R_2/R_1}{A(s)}} = \frac{1+R_2/R_1}{1 + \frac{s}{\left(\frac{\omega_t}{1+R_2/R_1}\right)}} = \frac{1+R_2/R_1}{1 + \frac{s}{\omega_0}}$

MOS DC Biasing

- this is all for NMOS. PMOS is backward
- cutoff: $V_{GS} < V_{th}$
 - * $I_D = 0$
- triode (linear): $V_{DS} < V_{GS} - V_{th}$
 - * $I_D = k'_n \frac{W}{L} \left((V_{GS} - V_{th})V_{DS} - \frac{V_{DS}^2}{2} \right)$
- active (saturation): $V_{DS} > V_{GS} - V_{th}$
 - * $I_D = \frac{k'_n}{2} \frac{W}{L} (V_{GS} - V_{th})^2$
 - * overdrive voltage $V_{ov} = V_{GS} - V_{th}$
- to show it's active: show that $V_{DS} > V_{ov}$ or $V_{DS} > V_{GS} - V_{th}$

MOS Small Signal

- $g_m = k'_n \frac{W}{L} (V_{GS} - V_t) = k'_p \frac{W}{L} (V_{SG} - V_t) = k'_n \frac{W}{L} (V_{ov})$
- CS: Common Source
 - * $R_i = R_G = R_{G1} || R_{G2}$
 - * $R_o = R_D$
 - * $\frac{V_o}{V_g} = \frac{R_D || R_L}{\frac{1}{g_m} + R_S}$
- CD: Common Drain (buffer)
 - * $R_i = R_G = R_{G1} || R_{G2}$
 - * $R_o = \frac{1}{g_m}$
 - * $\frac{V_o}{V_g} = \frac{R_L}{\frac{1}{g_m} + R_L}$
- CG: Common Gate
 - * $R_i = \frac{1}{g_m}$
 - * $R_o = R_D$

$$*\frac{V_o}{V_s}=\frac{R_D||R_L}{R_i}$$